

CEH2331A

-20V ▲ 42mΩ ▲ -5.5A ▲ Si MOSFET

SILICON Si MOSFET ▲ SMD type

P-channel enhancement mode

UL94V-0 rated flame retardant epoxy

TSOP6 package ▲ MSL 3

Super high dense cell density for extremely low $R_{DS(ON)}$

High power and current handling capability

MAXIMUM RATINGS

| Parameter ($T_A = 25^\circ\text{C}$, unless otherwise noted) | | Characteristics |
|----------------------------------------------------------------|----------------|---------------------------------------------|
| Drain-Source Voltage | V_{DS} | -20V |
| Gate-Source Voltage | V_{GS} | $\pm 8\text{V}$ |
| Continuous Drain Current | I_D | -5.5A |
| Pulsed Drain Current ^{Note 1} | I_{DM} | -22A |
| Maximum Power Dissipation | P_D | 2W |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55°C to $+150^\circ\text{C}$ |

THERMAL CHARACTERISTICS

| Parameter | Symbol | Limit |
|-----------------------------------------------------------|--------------|------------------------|
| Thermal Resistance, Junction-to-Ambient ^{Note 2} | R_{TH_JA} | 62.5°C/W |

APPLICATIONS

| Data Server Control | DC/DC Converter | Network Devices | Portable Products | USB Storage |
|---------------------|-----------------|-----------------|-------------------|-------------|
| | | | | |

PIN DESCRIPTION

| Circuit Diagram | Outline - Bottom View | Pin No. | Description |
|----------------------------------------|------------------------|----------------------------------------|----------------------------------------------------------------|
| <p>D (1,2,5,6) G (3) S (4)</p> | <p>6 5 4 1 2 3</p> | <p>1 2 3 4 5 6</p> | <p>Drain Drain Gate Source Drain Drain</p> |

ELECTRICAL CHARACTERISTICS ▲ $T_A = 25^\circ\text{C}$, unless otherwise noted

| Item | Condition | Symbol | Min. | Typ. | Max. | Unit |
|---------------------------------------------------------------|------------------------------------------------------------------|--------------|------|------|------|------------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = -250\mu A$ | BV_{DSS} | -20 | | | V |
| Zero Gate Voltage Drain Current | $V_{DS} = -20V, V_{GS} = 0V$ | I_{DSS} | | | -1 | μA |
| Gate Body Leakage Current, Forward | $V_{GS} = 8V, V_{DS} = 0V$ | I_{GSSF} | | | 100 | nA |
| Gate Body Leakage Current, Reverse | $V_{GS} = -8V, V_{DS} = 0V$ | I_{GSSR} | | | -100 | nA |
| On Characteristics ^{Note 3} | | | | | | |
| Gate Threshold Voltage | $V_{GS} = V_{DS}, I_D = -250\mu A$ | $V_{GS(th)}$ | -0.4 | | -1 | V |
| Static Drain-Source On-Resistance | $V_{GS} = -4.5V, I_D = -3.3A$ | $R_{DS(ON)}$ | | 33 | 42 | m Ω |
| Static Drain-Source On-Resistance | $V_{GS} = -2.5V, I_D = -2.8A$ | $R_{DS(ON)}$ | | 42 | 55 | m Ω |
| Static Drain-Source On-Resistance | $V_{GS} = -1.8V, I_D = -2A$ | $R_{DS(ON)}$ | | 55 | 75 | m Ω |
| Dynamic Characteristics ^{Note 4} | | | | | | |
| Input Capacitance | $V_{DS} = -10V, V_{GS} = 0V, f = 1MHz$ | C_{ISS} | | 795 | | pF |
| Output Capacitance | $V_{DS} = -10V, V_{GS} = 0V, f = 1MHz$ | C_{OSS} | | 100 | | pF |
| Reverse Transfer Capacitance | $V_{DS} = -10V, V_{GS} = 0V, f = 1MHz$ | C_{RSS} | | 90 | | pF |
| Switching Characteristics ^{Note 4} | | | | | | |
| Turn-On Delay Time | $V_{DD} = -10V, V_{GS} = -4.5V, I_D = -4A, R_{G(ext)} = 3\Omega$ | $t_{D(ON)}$ | | 12 | | ns |
| Turn-On Rise Time | $V_{DD} = -10V, V_{GS} = -4.5V, I_D = -4A, R_{G(ext)} = 3\Omega$ | t_R | | 8 | | ns |
| Turn-Off Delay Time | $V_{DD} = -10V, V_{GS} = -4.5V, I_D = -4A, R_{G(ext)} = 3\Omega$ | $t_{D(OFF)}$ | | 83 | | ns |
| Turn-Off Fall Time | $V_{DD} = -10V, V_{GS} = -4.5V, I_D = -4A, R_{G(ext)} = 3\Omega$ | t_F | | 41 | | ns |
| Total Gate Charge | $V_{DS} = -10V, V_{GS} = -4.5V, I_D = -4A$ | Q_G | | 10.2 | | nC |
| Gate Source Charge | $V_{DS} = -10V, V_{GS} = -4.5V, I_D = -4A$ | Q_{GS} | | 1 | | nC |
| Gate Drain Charge | $V_{DS} = -10V, V_{GS} = -4.5V, I_D = -4A$ | Q_{GD} | | 2.1 | | nC |
| Drain-Source Diode Characteristics and Maximum Ratings | | | | | | |
| Drain-Source Diode Forward Current ^{Note 2} | | I_S | | | -1.6 | A |
| Drain-Source Diode Forward Voltage ^{Note 3} | $V_{GS} = 0V, I_S = -1.6A$ | V_{SD} | | | -1.2 | V |

Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Surface Mounted on FR4 Board, $t \leq 5$ sec.
- 3: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
- 4: Guaranteed by design, not subject to production testing.

REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 1 • Output Characteristics

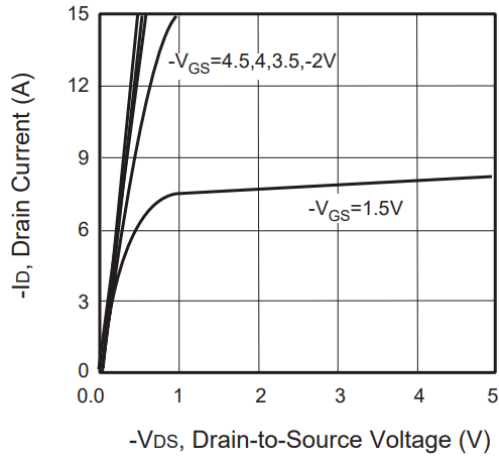


Fig. 2 • Transfer Characteristics

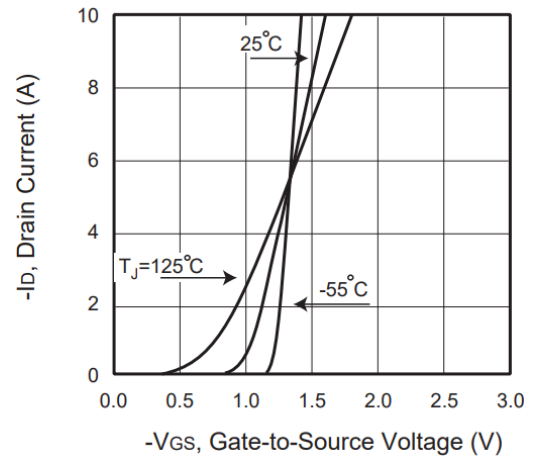


Fig. 3 • Capacitance

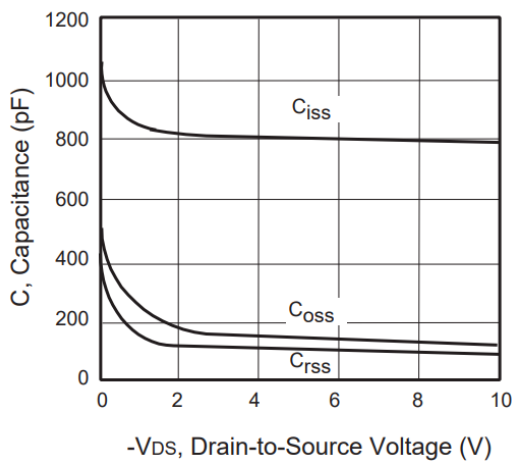


Fig. 4 • On-Resistance Variation with Temperature

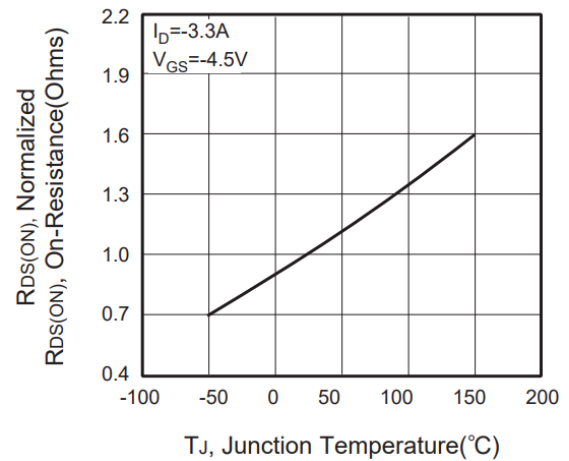


Fig. 5 • Gate Threshold Variation with Temperature

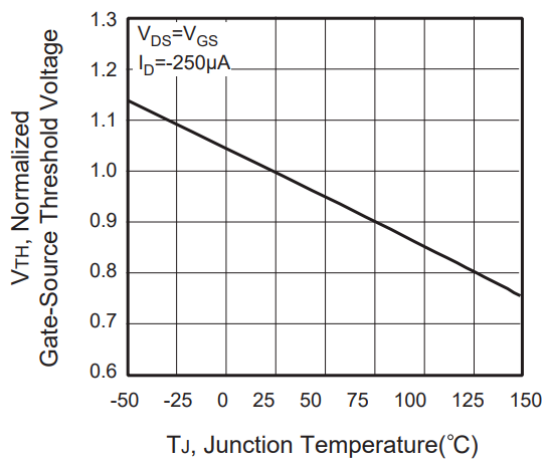
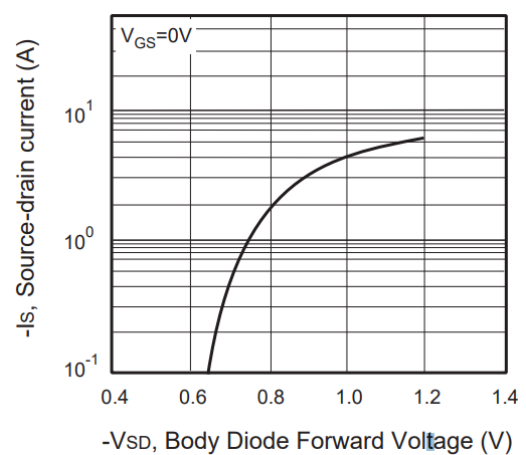


Fig. 6 • Body Diode Forward Voltage Variation with Source Current



REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 7 • Gate Charge

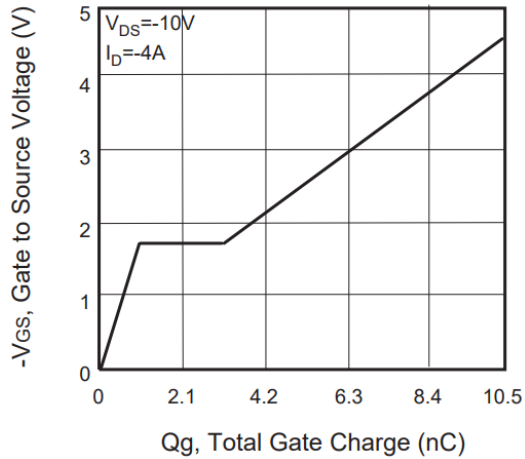


Fig. 8 • Maximum Safe Operating Area

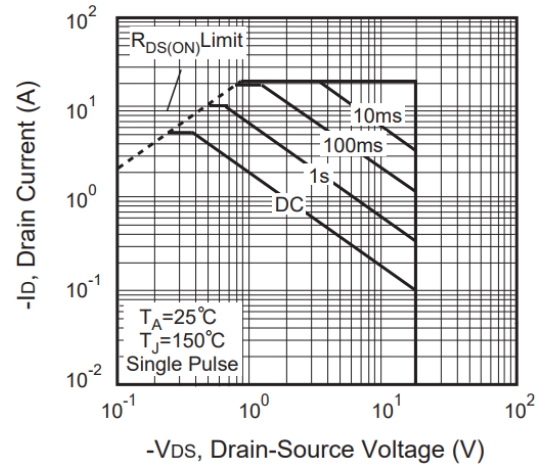


Fig. 9 • Breakdown Voltage Variation vs. Temperature

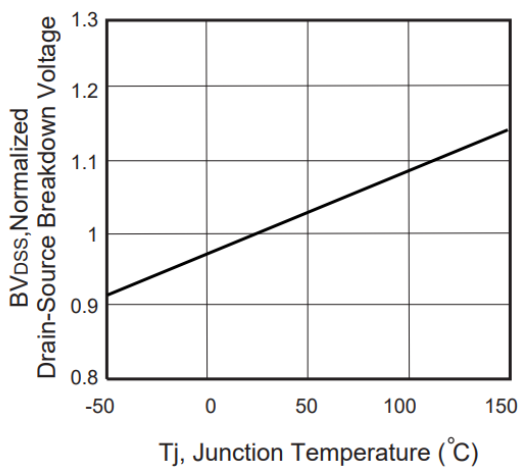


Fig. 10 • Switching Test Circuit

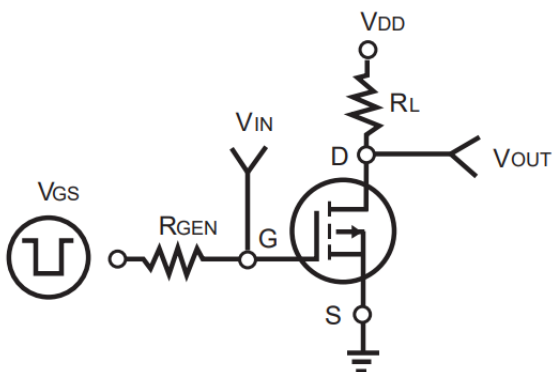
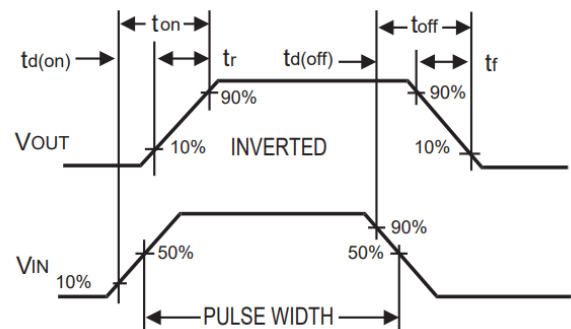
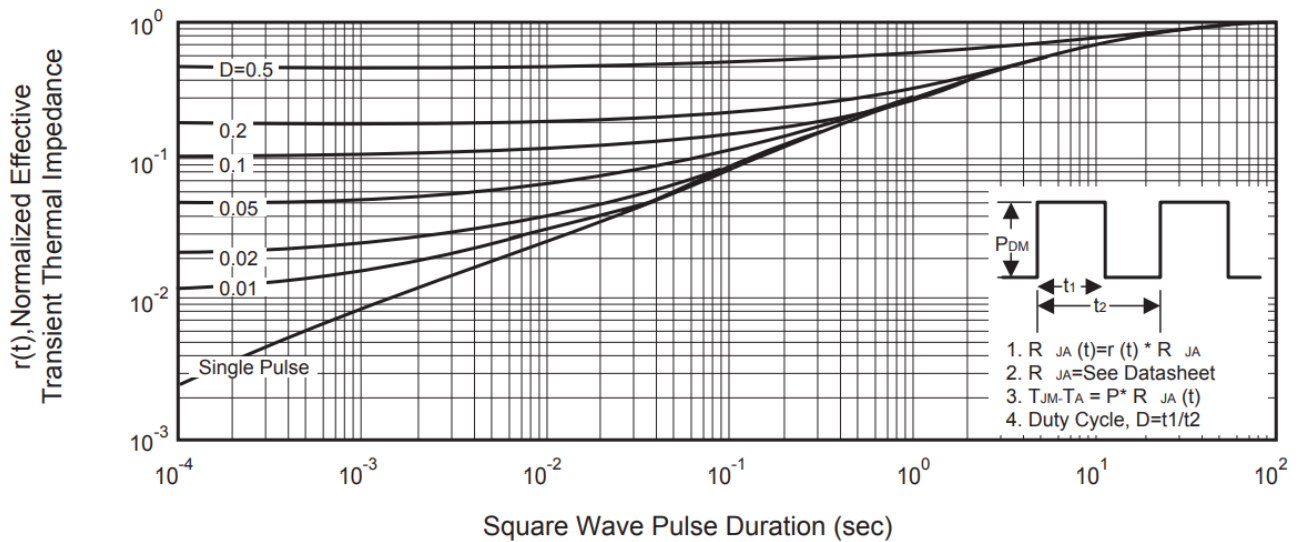


Fig. 11 • Switching Waveforms

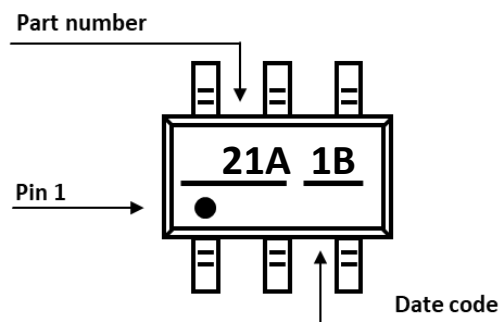


REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE

Fig. 12 • Normalized Thermal Transient Impedance Curve

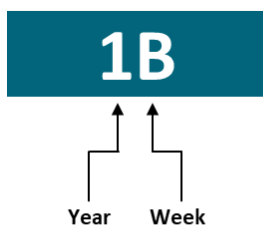


PART MARKING



DATE CODE

Example: 1B



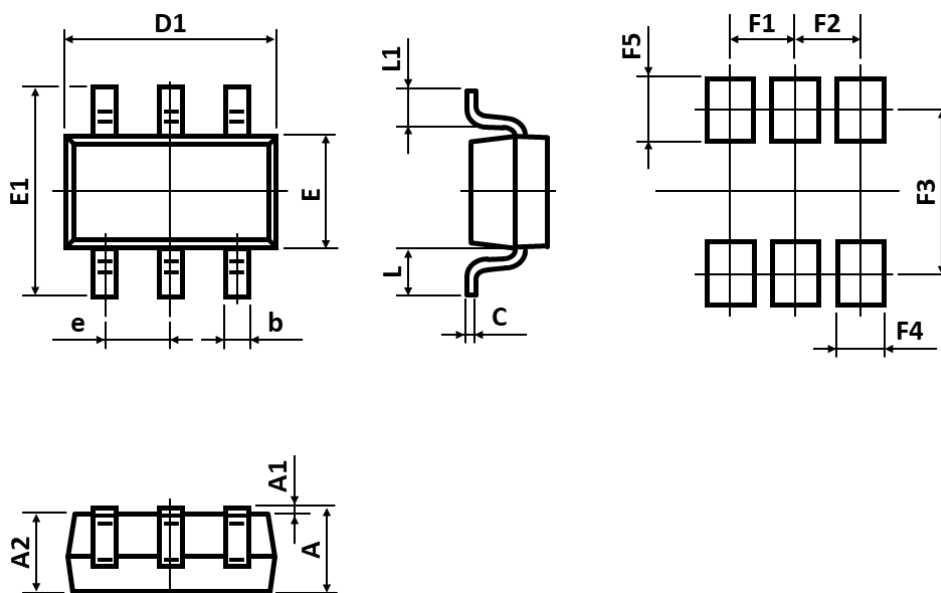
Coding list for „Week“

| A | B | C | D | E | F | G | H | I |
|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| 1-2 | 3-4 | 5-6 | 7-8 | 9-10 | 11-12 | 13-14 | 15-16 | 17-18 |
| J | K | L | M | N | O | P | Q | R |
| 19-20 | 21-22 | 23-24 | 25-26 | 27-28 | 29-30 | 31-32 | 33-34 | 35-36 |
| S | T | U | V | W | X | Y | Z | |
| 37-38 | 39-40 | 41-42 | 43-44 | 45-46 | 47-48 | 49-50 | 51-52 | |

Coding list for „Year“

| 0 | 1 | 2 | 3 | 4 |
|------|------|------|------|------|
| 2020 | 2021 | 2022 | 2023 | 2024 |
| 5 | 6 | 7 | 8 | 9 |
| 2025 | 2026 | 2027 | 2028 | 2029 |

PACKAGE OUTLINE AND RECOMMENDED PAD LAYOUT



| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|-----------------------|-----------------------|-----------------------|
| A | 0.800 | - | 1.250 |
| A1 | 0.000 | - | 0.130 |
| A2 | 0.700 | - | 1.200 |
| b | 0.300 | - | 0.500 |
| C | 0.090 | - | 0.200 |
| D1 | 2.800 | - | 3.100 |

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|-----------------------|-----------------------|-----------------------|
| F1 | - | 0.950 | - |
| F2 | - | 0.950 | - |
| F3 | - | 2.600 | - |

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|-----------------------|-----------------------|-----------------------|
| E | 1.500 | - | 1.700 |
| E1 | 2.500 | - | 3.100 |
| e | 0.950 (TYP) | | |
| L | 0.350 | - | 0.800 |
| L1 | 0.300 | - | 0.550 |

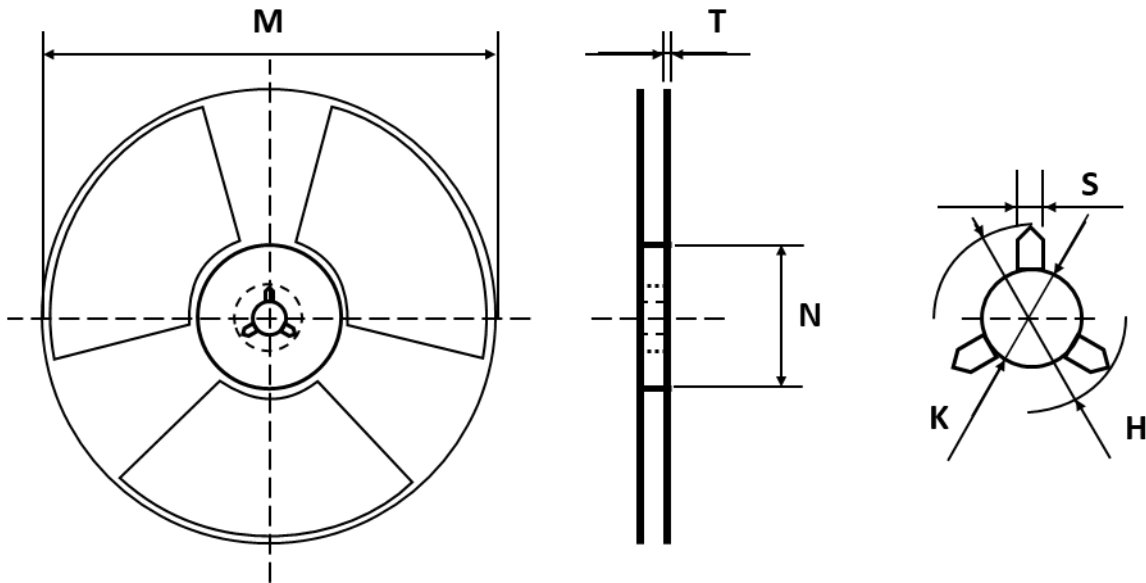
| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|-----------------------|-----------------------|-----------------------|
| F4 | - | 0.700 | - |
| F5 | - | 1.000 | - |

Notes: 1. The suggested land pattern dimensions have been provided for reference only.
2. For further information, please reference document IPC-7351A.

ORDERING INFORMATION

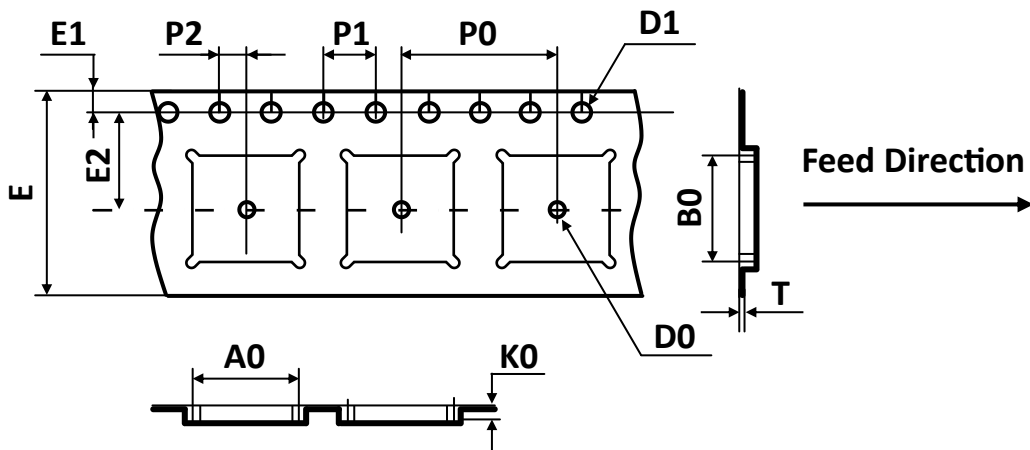
| Part Number | Package | Packing | Reel Qty. | Inner Box Qty. |
|-------------|---------|---------|-----------|----------------|
| CEH2321A | TSOP 6 | Reel | 3,000pcs | 15,000pcs |

REEL DIMENSIONS ▲ All dimensions in mm



| Tape Size | Reel Size | M | N | T | H | K | S |
|-----------|-----------|------------------|-----------------|---------------|----------------|----------------|---------------|
| 8mm | Ø180 | Ø178.00 ±1.00 | Ø54.00 ±0.50 | 1.20 ±0.20 | 20.00 ±1.00 | 13.30 ±0.30 | 3.00 ±1.00 |

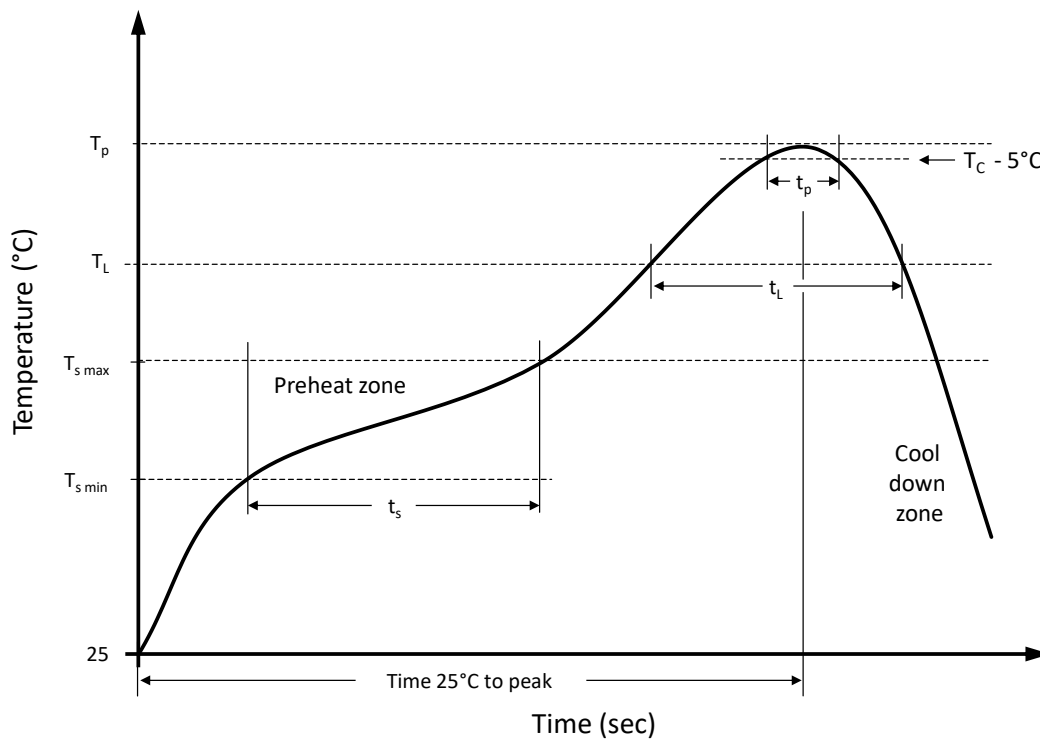
TAPE DIMENSIONS ▲ All dimensions in mm



| Package | A0 | B0 | K0 | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | T |
|---------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|
| TSOP6 | 3.20 ±0.10 | 3.20 ±0.10 | 1.35 ±0.10 | 1.00 ±0.10 | 1.50 ±0.10 | 8.00 ±0.10 | 1.75 ±0.10 | 3.50 ±0.10 | 4.00 ±0.10 | 4.00 ±0.10 | 2.00 ±0.05 | 0.20 ±0.02 |

Note: All dimensions meet EIA-481-D requirements.

RECOMMENDED REFLOW SOLDERING PROFILE



Recommended reflow soldering conditions ▲ Refer to JEDEC J-STD-020E

| Profile Features | | Sn-Pb Eutetic Assembly | Pb-Free Assembly |
|--------------------------------------------------------------------------|--------------|------------------------|------------------|
| Preheat temperature min. | $T_{s\ min}$ | 100 °C | 150 °C |
| Preheat temperature max. | $T_{s\ max}$ | 150 °C | 200 °C |
| Preheat time t_s from $T_{s\ min}$ to $T_{s\ max}$ | t_s | 120 seconds | 120 seconds |
| Ramp-up rate (T_L to T_p) | | max. 3 °C/second | max. 3 °C/second |
| Liquidous temperature | T_L | 183 °C | 217 °C |
| Time t_L maintained above T_L | t_L | 150 seconds max. | 150 seconds max. |
| Peak package body temperature | T_p | 235°C | 260°C |
| Timeframe of within 5°C below and up to max actual peak body temperature | t_p | 20 seconds max. | 30 seconds max. |
| Ramp-down rate (T_L to T_p) | | max. 6 °C/second | max. 6 °C/second |
| Time 25°C to peak temperature | | max. 6 minutes | max. 8 minutes |

REVISION TABLE

| Revision | Date | Status | Notes |
|----------|------------|-----------------|---------------------|
| 001 | 30/09/2022 | Initial release | Initial publication |
| | | | |
| | | | |
| | | | |
| | | | |
| | | | |

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